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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	150MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I ² C, Microwire, SD, SPI, SSI, SSP, UART/USART, USB OTG
Peripherals	Brown-out Detect/Reset, DMA, I ² S, Motor Control PWM, POR, PWM, WDT
Number of I/O	80
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	136K x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 3.6V
Data Converters	A/D 16x10b; D/A 1x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	256-LBGA
Supplier Device Package	256-LBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/lpc1837fet256-551

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP144	LQFP208		Reset state [1]	Type	Description
P1_16	M7	H9	64	90	[2]	N; PU	I/O	GPIO0[3] — General purpose digital input/output pin.
							I	U2_RXD — Receiver input for USART2.
							-	R — Function reserved.
							I	ENET_CRS — Ethernet Carrier Sense (MII interface).
							O	T0_MAT0 — Match output 0 of timer 0.
							-	R — Function reserved.
							I/O	EMC_D9 — External memory data line 9.
P1_17	M8	H10	66	93	[3]	N; PU	I/O	GPIO0[12] — General purpose digital input/output pin.
							I/O	U2_UCLK — Serial clock input/output for USART2 in synchronous mode.
							-	R — Function reserved.
							I/O	ENET_MDIO — Ethernet MIIM data input and output.
							I	T0_CAP3 — Capture input 3 of timer 0.
							O	CAN1_TD — CAN1 transmitter output.
							-	R — Function reserved.
P1_18	N12	J10	67	95	[2]	N; PU	I/O	GPIO0[13] — General purpose digital input/output pin.
							I/O	U2_DIR — RS-485/EIA-485 output enable/direction control for USART2.
							-	R — Function reserved.
							O	ENET_TXD0 — Ethernet transmit data 0 (RMII/MII interface).
							O	T0_MAT3 — Match output 3 of timer 0.
							I	CAN1_RD — CAN1 receiver input.
							-	R — Function reserved.
P1_19	M11	K9	68	96	[2]	N; PU	I/O	EMC_D10 — External memory data line 10.
							I	ENET_TX_CLK (ENET_REF_CLK) — Ethernet Transmit Clock (MII interface) or Ethernet Reference Clock (RMII interface).
							I/O	SSP1_SCK — Serial clock for SSP1.
							-	R — Function reserved.
							-	R — Function reserved.
							O	CLKOUT — Clock output pin.
							-	R — Function reserved.
P1_19	M11	K9	68	96	[2]	N; PU	O	I2S0_RX_MCLK — I ² S receive master clock.
							I/O	I2S1_TX_SCK — Transmit Clock. It is driven by the master and received by the slave. Corresponds to the signal SCK in the I ² S-bus specification.

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP144	LQFP208		Reset state [1]	Type	Description
P2_8	J16	C6	98	140	[2]	N; PU	-	R — Function reserved. External boot pin (see Table 5)
							O	CTOUT_0 — SCTimer/PWM output 0. Match output 0 of timer 0.
							I/O	U3_DIR — RS-485/EIA-485 output enable/direction control for USART3.
							I/O	EMC_A8 — External memory address line 8.
							I/O	GPIO5[7] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
P2_9	H16	B10	102	144	[2]	N; PU	I/O	GPIO1[10] — General purpose digital input/output pin. External boot pin (see Table 5).
							O	CTOUT_3 — SCTimer/PWM output 3. Match output 3 of timer 0.
							I/O	U3_BAUD — Baud pin for USART3.
							I/O	EMC_A0 — External memory address line 0.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
P2_10	G16	E8	104	146	[2]	N; PU	I/O	GPIO0[14] — General purpose digital input/output pin.
							O	CTOUT_2 — SCTimer/PWM output 2. Match output 2 of timer 0.
							O	U2_TXD — Transmitter output for USART2.
							I/O	EMC_A1 — External memory address line 1.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
P2_11	F16	A9	105	148	[2]	N; PU	I/O	GPIO1[11] — General purpose digital input/output pin.
							O	CTOUT_5 — SCTimer/PWM output 5. Match output 3 of timer 3.
							I	U2_RXD — Receiver input for USART2.
							I/O	EMC_A2 — External memory address line 2.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP144	LQFP208		Reset state [1]	Type	Description
P5_7	R12	-	65	91	[2]	N; PU	I/O	GPIO2[7] — General purpose digital input/output pin.
							O	MCOA2 — Motor control PWM channel 2, output A.
							I/O	EMC_D11 — External memory data line 11.
							-	R — Function reserved.
							I	U1_RXD — Receiver input for UART1.
							O	T1_MAT3 — Match output 3 of timer 1.
							-	R — Function reserved.
							-	R — Function reserved.
P6_0	M12	H7	73	105	[2]	N; PU	-	R — Function reserved.
							O	I2S0_RX_MCLK — I ² S receive master clock.
							-	R — Function reserved.
							-	R — Function reserved.
							I/O	I2S0_RX_SCK — Receive Clock. It is driven by the master and received by the slave. Corresponds to the signal SCK in the <i>I²S-bus specification</i> .
							-	R — Function reserved.
							-	R — Function reserved.
P6_1	R15	G5	74	107	[2]	N; PU	I/O	GPIO3[0] — General purpose digital input/output pin.
							O	EMC_DYCS1 — SDRAM chip select 1.
							I/O	U0_UCLK — Serial clock input/output for USART0 in synchronous mode.
							I/O	I2S0_RX_WS — Receive Word Select. It is driven by the master and received by the slave. Corresponds to the signal WS in the <i>I²S-bus specification</i> .
							-	R — Function reserved.
							I	T2_CAP0 — Capture input 2 of timer 2.
							-	R — Function reserved.
P6_2	L13	J9	78	111	[2]	N; PU	I/O	GPIO3[1] — General purpose digital input/output pin.
							O	EMC_CKEOUT1 — SDRAM clock enable 1.
							I/O	U0_DIR — RS-485/EIA-485 output enable/direction control for USART0.
							I/O	I2S0_RX_SDA — I ² S Receive data. It is driven by the transmitter and read by the receiver. Corresponds to the signal SD in the <i>I²S-bus specification</i> .
							-	R — Function reserved.
							I	T2_CAP1 — Capture input 1 of timer 2.
							-	R — Function reserved.
							-	R — Function reserved.

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP144	LQFP208		Reset state [1]	Type	Description
P7_5	A7	-	133	191	[5]	N; PU	I/O	GPIO3[13] — General purpose digital input/output pin.
							O	CTOUT_12 — SCTimer/PWM output 12. Match output 3 of timer 3.
							-	R — Function reserved.
							O	LCD_VD8 — LCD data.
							O	LCD_VD23 — LCD data.
							O	TRACEDATA[1] — Trace data, bit 1.
							-	R — Function reserved.
							-	R — Function reserved.
							AI	ADC0_3 — ADC0 and ADC1, input channel 3. Configure the pin as GPIO input and use the ADC function select register in the SCU to select the ADC.
P7_6	C7	-	134	194	[2]	N; PU	I/O	GPIO3[14] — General purpose digital input/output pin.
							O	CTOUT_11 — SCTimer/PWM output 1. Match output 3 of timer 2.
							-	R — Function reserved.
							O	LCD_LP — Line synchronization pulse (STN). Horizontal synchronization pulse (TFT).
							-	R — Function reserved.
							O	TRACEDATA[2] — Trace data, bit 2.
							-	R — Function reserved.
P7_7	B6	-	140	201	[5]	N; PU	I/O	GPIO3[15] — General purpose digital input/output pin.
							O	CTOUT_8 — SCTimer/PWM output 8. Match output 0 of timer 2.
							-	R — Function reserved.
							O	LCD_PWR — LCD panel power enable.
							-	R — Function reserved.
							O	TRACEDATA[3] — Trace data, bit 3.
							O	ENET_MDC — Ethernet MIIM clock.
							-	R — Function reserved.
							AI	ADC1_6 — ADC1 and ADC0, input channel 6. Configure the pin as GPIO input and use the ADC function select register in the SCU to select the ADC.

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP144	LQFP208		Reset state [1]	Type	Description
P9_3	M6	-	-	79	[2]	N; PU	I/O	GPIO4[15] — General purpose digital input/output pin.
							O	MCOA0 — Motor control PWM channel 0, output A.
							O	USB1_IND1 — USB1 Port indicator LED control output 1.
							-	R — Function reserved.
							-	R — Function reserved.
							I	ENET_RXD2 — Ethernet receive data 2 (MII interface).
							-	R — Function reserved.
							O	U3_TXD — Transmitter output for USART3.
P9_4	N10	-	-	92	[2]	N; PU	-	R — Function reserved.
							O	MCOB0 — Motor control PWM channel 0, output B.
							O	USB1_IND0 — USB1 Port indicator LED control output 0.
							-	R — Function reserved.
							I/O	GPIO5[17] — General purpose digital input/output pin.
							O	ENET_TXD2 — Ethernet transmit data 2 (MII interface).
							-	R — Function reserved.
P9_5	M9	-	69	98	[2]	N; PU	I	U3_RXD — Receiver input for USART3.
							-	R — Function reserved.
							O	MCOA1 — Motor control PWM channel 1, output A.
							O	USB1_PPWR — VBUS drive signal (towards external charge pump or power management unit); indicates that VBUS must be driven (active HIGH). Add a pull-down resistor to disable the power switch at reset. This signal has opposite polarity compared to the USB_PPWR used on other NXP LPC parts.
							-	R — Function reserved.
							I/O	GPIO5[18] — General purpose digital input/output pin.
							O	ENET_TXD3 — Ethernet transmit data 3 (MII interface).
							-	R — Function reserved.
P9_6	L11	-	72	103	[2]	N; PU	O	U0_TXD — Transmitter output for USART0.
							I/O	GPIO4[11] — General purpose digital input/output pin.
							O	MCOB1 — Motor control PWM channel 1, output B.
							I	USB1_PWR_FAULT — USB1 Port power fault signal indicating over-current condition; this signal monitors over-current on the USB1 bus (external circuitry required to detect over-current condition).
							-	R — Function reserved.
							-	R — Function reserved.
							I	ENET_COL — Ethernet Collision detect (MII interface).
							-	R — Function reserved.
							I	U0_RXD — Receiver input for USART0.

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP144	LQFP208		Reset state [1]	Type	Description
PD_0	N2	-	-	-	[2]	N; PU	-	R — Function reserved.
							O	CTOUT_15 — SCTimer/PWM output 15. Match output 3 of timer 3.
							O	EMC_DQMOUT2 — Data mask 2 used with SDRAM and static devices.
							-	R — Function reserved.
							I/O	GPIO6[14] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
PD_1	P1	-	-	-	[2]	N; PU	-	R — Function reserved.
							-	R — Function reserved.
							O	EMC_CKEOUT2 — SDRAM clock enable 2.
							-	R — Function reserved.
							I/O	GPIO6[15] — General purpose digital input/output pin.
							O	SD_POW — SD/MMC power monitor output.
							-	R — Function reserved.
PD_2	R1	-	-	-	[2]	N; PU	-	R — Function reserved.
							O	CTOUT_7 — SCTimer/PWM output 7. Match output 3 of timer 1.
							I/O	EMC_D16 — External memory data line 16.
							-	R — Function reserved.
							I/O	GPIO6[16] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
PD_3	P4	-	-	-	[2]	N; PU	-	R — Function reserved.
							O	CTOUT_6 — SCTimer/PWM output 7. Match output 2 of timer 1.
							I/O	EMC_D17 — External memory data line 17.
							-	R — Function reserved.
							I/O	GPIO6[17] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP144	LQFP208		Reset state [1]	Type	Description
PD_4	T2	-	-	-	[2]	N; PU	-	R — Function reserved.
							O	CTOUT_8 — SCTimer/PWM output 8. Match output 0 of timer 2.
							I/O	EMC_D18 — External memory data line 18.
							-	R — Function reserved.
							I/O	GPIO6[18] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
PD_5	P6	-	-	-	[2]	N; PU	-	R — Function reserved.
							O	CTOUT_9 — SCTimer/PWM output 9. Match output 3 of timer 3.
							I/O	EMC_D19 — External memory data line 19.
							-	R — Function reserved.
							I/O	GPIO6[19] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
PD_6	R6	-	-	68	[2]	N; PU	-	R — Function reserved.
							O	CTOUT_10 — SCTimer/PWM output 10. Match output 3 of timer 3.
							I/O	EMC_D20 — External memory data line 20.
							-	R — Function reserved.
							I/O	GPIO6[20] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
PD_7	T6	-	-	72	[2]	N; PU	-	R — Function reserved.
							I	CTIN_5 — SCTimer/PWM input 5. Capture input 2 of timer 2.
							I/O	EMC_D21 — External memory data line 21.
							-	R — Function reserved.
							I/O	GPIO6[21] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP144	LQFP208		Reset state [1]	Type	Description
PD_8	P8	-	-	74	[2]	N; PU	-	R — Function reserved.
							I	CTIN_6 — SCTimer/PWM input 6. Capture input 1 of timer 3.
							I/O	EMC_D22 — External memory data line 22.
							-	R — Function reserved.
							I/O	GPIO6[22] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
PD_9	T11	-	-	84	[2]	N; PU	-	R — Function reserved.
							O	CTOUT_13 — SCTimer/PWM output 13. Match output 3 of timer 3.
							I/O	EMC_D23 — External memory data line 23.
							-	R — Function reserved.
							I/O	GPIO6[23] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
PD_10	P11	-	-	86	[2]	N; PU	-	R — Function reserved.
							I	CTIN_1 — SCTimer/PWM input 1. Capture input 1 of timer 0. Capture input 1 of timer 2.
							O	EMC_BLS3 — LOW active Byte Lane select signal 3.
							-	R — Function reserved.
							I/O	GPIO6[24] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
PD_11	N9	-	-	88	[2]	N; PU	-	R — Function reserved.
							-	R — Function reserved.
							O	EMC_CS3 — LOW active Chip Select 3 signal.
							-	R — Function reserved.
							I/O	GPIO6[25] — General purpose digital input/output pin.
							I/O	USB1_ULPI_D0 — ULPI link bidirectional data line 0.
							O	CTOUT_14 — SCTimer/PWM output 14. Match output 2 of timer 3.
							-	R — Function reserved.

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP144	LQFP208		Reset state [1]	Type	Description
PD_16	R14	-	-	104	[2]	N; PU	-	R — Function reserved.
							-	R — Function reserved.
							I/O	EMC_A16 — External memory address line 16.
							-	R — Function reserved.
							I/O	GPIO6[30] — General purpose digital input/output pin.
							O	SD_VOLT2 — SD/MMC bus voltage select output 2.
							O	CTOUT_12 — SCTimer/PWM output 12. Match output 3 of timer 3.
PE_0	P14	-	-	106	[2]	N; PU	-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							I/O	EMC_A18 — External memory address line 18.
							I/O	GPIO7[0] — General purpose digital input/output pin.
							O	CAN1_TD — CAN1 transmitter output.
							-	R — Function reserved.
PE_1	N14	-	-	112	[2]	N; PU	-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							I/O	EMC_A19 — External memory address line 19.
							I/O	GPIO7[1] — General purpose digital input/output pin.
							I	CAN1_RD — CAN1 receiver input.
							-	R — Function reserved.
PE_2	M14	-	-	115	[2]	N; PU	-	R — Function reserved.
							I	ADCTRIG0 — ADC trigger input 0.
							I	CAN0_RD — CAN receiver input.
							-	R — Function reserved.
							I/O	EMC_A20 — External memory address line 20.
							I/O	GPIO7[2] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.

7.12 Memory mapping

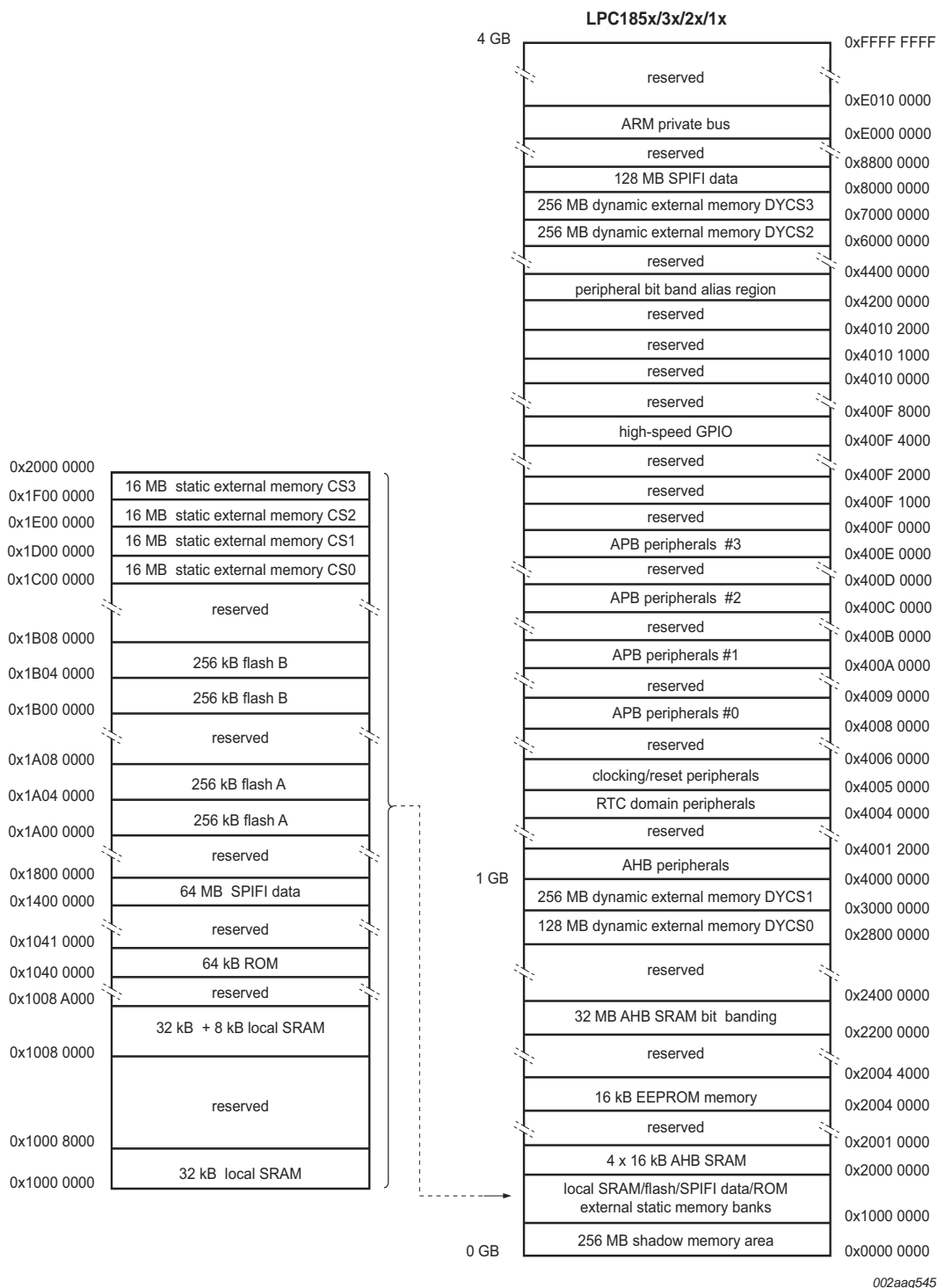


Fig 7. LPC185x/3x/2x/1x Memory mapping (overview)

- Read and write buffers to reduce latency and to improve performance.
- 8/16/32 data and 24 address lines-wide static memory support.
- 16-bit and 32-bit wide chip select SDRAM memory support.
- Static memory features include:
 - Asynchronous page mode read.
 - Programmable Wait States.
 - Bus turnaround delay.
 - Output enable and write enable delays.
 - Extended wait.
- Four chip selects for synchronous memory and four chip selects for static memory devices.
- Power-saving modes dynamically control CKE and CLKOUT to SDRAMs.
- Software-controlled dynamic memory self-refresh mode.
- Controller supports 2048 (A0 to A10), 4096 (A0 to A11), and 8192 (A0 to A12) row address synchronous memory parts. Those are typically 512 MB, 256 MB, and 128 MB parts.
- Separate reset domains allow auto-refresh through a chip reset if desired.

Note: Synchronous static memory devices (synchronous burst mode) are not supported.

7.15.6 High-speed USB Host/Device/OTG interface (USB0)

Remark: USB0 is available on the following parts: LPC185x, LPC183x, LPC182x. USB0 is not available on the LPC181x parts.

The USB OTG module allows the part to connect directly to a USB host such as a PC (in device mode) or to a USB device in host mode.

7.15.6.1 Features

- On-chip UTMI+ compliant high-speed transceiver (PHY).
- Complies with *Universal Serial Bus specification 2.0*.
- Complies with *USB On-The-Go supplement*.
- Complies with *Enhanced Host Controller Interface Specification*.
- Supports auto USB 2.0 mode discovery.
- Supports all high-speed USB-compliant peripherals.
- Supports all full-speed USB-compliant peripherals.
- Supports software Host Negotiation Protocol (HNP) and Session Request Protocol (SRP) for OTG peripherals.
- Supports interrupts.
- Supports Start Of Frame (SOF) frame length adjust.
- This module has its own, integrated DMA engine.
- USB interface electrical test software included in ROM USB stack.

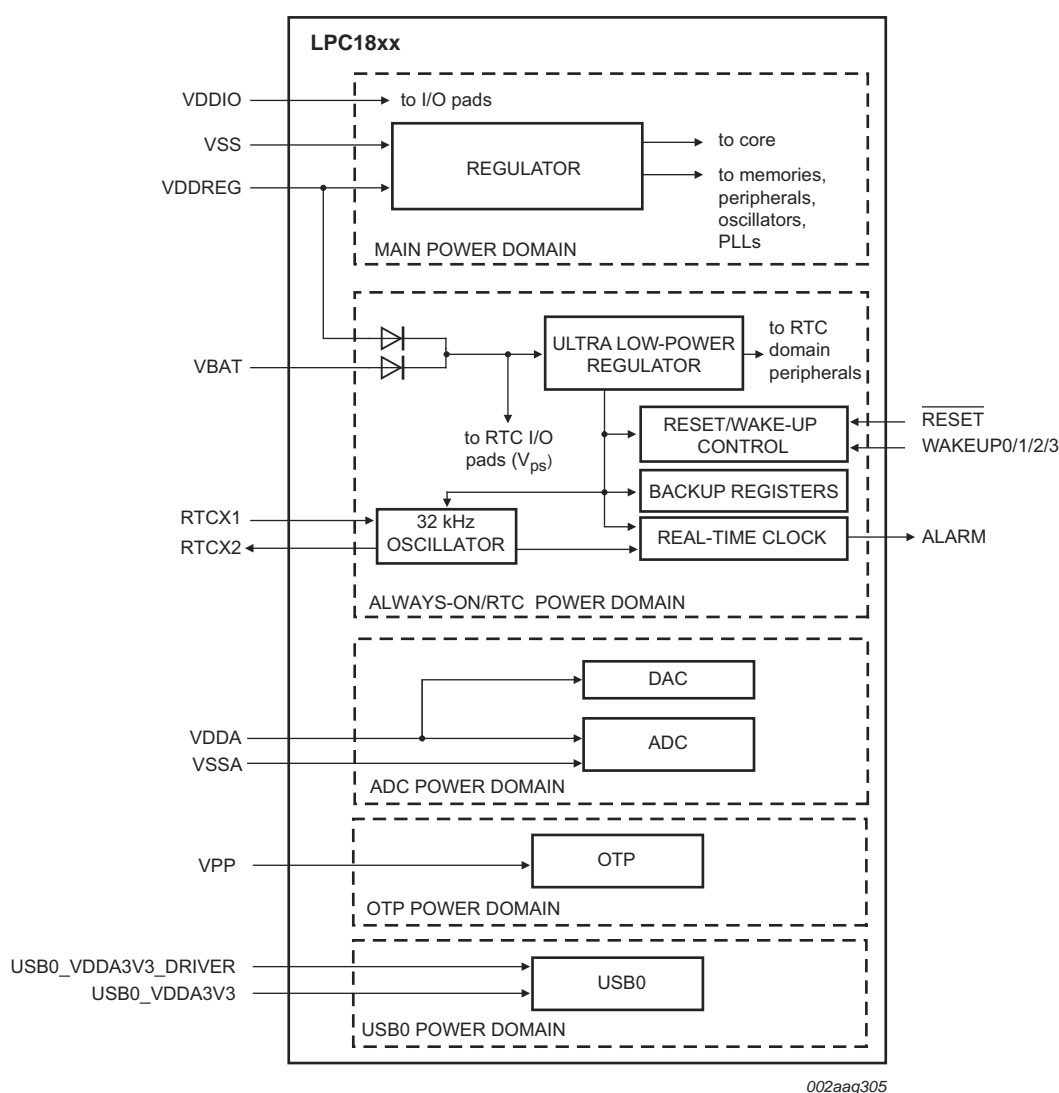


Fig 9. LPC185x/3x/2x/1x Power domains

The LPC185x/3x/2x/1x support four reduced power modes: Sleep, Deep-sleep, Power-down, and Deep power-down.

The LPC185x/3x/2x/1x can wake up from Deep-sleep, Power-down, and Deep power-down modes via the WAKEUP[3:0] pins and interrupts generated by battery powered blocks in the RTC power domain.

7.20.10 Code security (Code Read Protection - CRP)

CRP enables different levels of security so that access to the on-chip flash and use of the JTAG and ISP can be restricted. CRP is invoked by programming a specific pattern into a dedicated flash location. IAP commands are not affected by CRP.

Table 11. Static characteristics ...continued

 $T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+105\text{ }^{\circ}\text{C}$, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ ^[1]	Max	Unit
I _{DD(IO)}	I/O supply current	deep sleep mode		-	< 0.1	-	μA
		power-down mode		-	< 0.1	-	μA
		deep power-down mode		-	< 0.1	-	μA
I _{DDA}	Analog supply current	on pin VDDA; deep sleep mode	[9]	-	0.4	-	μA
		power-down mode	[9]	-	0.4	-	μA
		deep power-down mode	[9]	-	0.007	-	μA
RESET pin							
V _{IH}	HIGH-level input voltage		[8]	0.8 × (V _{ps} – 0.35)	-	5.5	V
V _{IL}	LOW-level input voltage		[8]	0	-	0.3 × (V _{ps} – 0.1)	V
V _{hys}	hysteresis voltage		[8]	0.05 × (V _{ps} – 0.35)	-	-	V
Standard I/O pins - normal drive strength							
C _I	input capacitance			-	-	2	pF
I _{LL}	LOW-level leakage current	V _I = 0 V; on-chip pull-up resistor disabled		-	3	-	nA
I _{LH}	HIGH-level leakage current	V _I = V _{DD(IO)} ; on-chip pull-down resistor disabled		-	3	-	nA
		V _I = 5 V; T _{amb} = 25 °C		-	0.5	-	nA
		V _I = 5 V; T _{amb} = 105 °C		-	40	-	nA
I _{OZ}	OFF-state output current	V _O = 0 V to V _{DD(IO)} ; on-chip pull-up/down resistors disabled; absolute value		-	3	-	nA
V _I	input voltage	pin configured to provide a digital function; V _{DD(IO)} ≥ 2.4 V		0	-	5.5	V
		V _{DD(IO)} = 0 V		0	-	3.6	V
V _O	output voltage	output active		0	-	V _{DD(IO)}	V
V _{IH}	HIGH-level input voltage			0.7 × V _{DD(IO)}	-	5.5	V
V _{IL}	LOW-level input voltage			0	-	0.3 × V _{DD(IO)}	V
V _{hys}	hysteresis voltage			0.1 × V _{DD(IO)}	-	-	V
V _{OH}	HIGH-level output voltage	I _{OH} = –6 mA		V _{DD(IO)} – 0.4	-	-	V
V _{OL}	LOW-level output voltage	I _{OL} = 6 mA		-	-	0.4	V
I _{OH}	HIGH-level output current	V _{OH} = V _{DD(IO)} – 0.4 V		–6	-	-	mA

11. Dynamic characteristics

11.1 Flash/EEPROM memory

Table 15. Flash characteristics

$T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+105\text{ }^{\circ}\text{C}$, unless otherwise specified. $V_{DD(REG)(3V3)} = 2.4\text{ V}$ to 3.6 V for read operations; $V_{DD(REG)(3V3)} = 2.7\text{ V}$ to 3.6 V for erase/program operations.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
N_{endu}	endurance	sector erase/program	[1]	10 000	-	-	cycles
		page erase/program; page in large sector		1000	-	-	cycles
		page erase/program; page in small sector		10 000	-	-	cycles
t_{ret}	retention time	powered		10	-	-	years
		unpowered		10	-	-	years
t_{er}	erase time	page, sector, or multiple consecutive sectors		-	100	-	ms
t_{prog}	programming time		[2]	-	1	-	ms

[1] Number of erase/program cycles.

[2] Programming times are given for writing 512 bytes from RAM to the flash. Data must be written to the flash in blocks of 512 bytes.

Table 16. EEPROM characteristics

$T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+105\text{ }^{\circ}\text{C}$; $V_{DD(REG)(3V3)} = 2.7\text{ V}$ to 3.6 V .

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
f_{clk}	clock frequency			800	1500	1600	kHz
N_{endu}	endurance			100 000	-	-	cycles
t_{ret}	retention time	$T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$		20	-	-	years
		$85\text{ }^{\circ}\text{C} < T_{amb} \leq 105\text{ }^{\circ}\text{C}$		10	-	-	years
t_a	access time	read		-	120	-	ns
		erase/program; $f_{clk} = 1500\text{ kHz}$		-	1.99	-	ms
		erase/program; $f_{clk} = 1600\text{ kHz}$		-	1.87	-	ms
t_{wait}	wait time	read; RPHASE1	[1]	35	-	-	ns
		read; RPHASE2	[1]	70	-	-	ns
		write; PHASE1	[1]	20	-	-	ns
		write; PHASE2	[1]	40	-	-	ns
		write; PHASE3	[1]	10	-	-	ns

[1] See the LPC18xx user manual how to program the wait states for the different read (RPHASEx) and erase/program phases (PHASEx)

Table 29. Dynamic characteristics: Dynamic external memory interface

Simulated data over temperature and process range; $C_L = 10$ pF for $\overline{EMC_DYCSn}$, $\overline{EMC_RAS}$, $\overline{EMC_CAS}$, $\overline{EMC_WE}$, $\overline{EMC_An}$; $C_L = 9$ pF for $\overline{EMC_Dn}$; $C_L = 5$ pF for $\overline{EMC_DQMOUTn}$, $\overline{EMC_CLKn}$, $\overline{EMC_CKEOUTn}$; $T_{amb} = -40$ °C to $+105$ °C; $2.4\text{ V} \leq V_{DD(REG)(3V3)} \leq 3.6\text{ V}$; $V_{DD(IO)} = 3.3\text{ V} \pm 10\%$; $RD = 1$ (see LPC18xx User manual); $\overline{EMC_CLKn}$ delays $CLK0_DELAY = CLK1_DELAY = CLK2_DELAY = CLK3_DELAY = 0$.

Symbol	Parameter	Min	Typ	Max	Unit
$T_{cy(clk)}$	clock cycle time	8.4	-	-	ns
Common to read and write cycles					
$t_d(DYCSV)$	dynamic chip select valid delay time	-	$3.1 + 0.5 \times T_{cy(clk)}$	$5.1 + 0.5 \times T_{cy(clk)}$	ns
$t_h(DYCS)$	dynamic chip select hold time	$0.3 + 0.5 \times T_{cy(clk)}$	$0.9 + 0.5 \times T_{cy(clk)}$	-	ns
$t_d(RASV)$	row address strobe valid delay time	-	$3.1 + 0.5 \times T_{cy(clk)}$	$4.9 + 0.5 \times T_{cy(clk)}$	ns
$t_h(RAS)$	row address strobe hold time	$0.5 + 0.5 \times T_{cy(clk)}$	$1.1 + 0.5 \times T_{cy(clk)}$	-	ns
$t_d(CASV)$	column address strobe valid delay time	-	$2.9 + 0.5 \times T_{cy(clk)}$	$4.6 + 0.5 \times T_{cy(clk)}$	ns
$t_h(CAS)$	column address strobe hold time	$0.3 + 0.5 \times T_{cy(clk)}$	$0.9 + 0.5 \times T_{cy(clk)}$	-	ns
$t_d(WEV)$	write enable valid delay time	-	$3.2 + 0.5 \times T_{cy(clk)}$	$5.9 + 0.5 \times T_{cy(clk)}$	ns
$t_h(WE)$	write enable hold time	$1.3 + 0.5 \times T_{cy(clk)}$	$1.4 + 0.5 \times T_{cy(clk)}$	-	ns
$t_d(DQMOUTV)$	DQMOUT valid delay time	-	$3.1 + 0.5 \times T_{cy(clk)}$	$5.0 + 0.5 \times T_{cy(clk)}$	ns
$t_h(DQMOUT)$	DQMOUT hold time	$0.2 + 0.5 \times T_{cy(clk)}$	$0.8 + 0.5 \times T_{cy(clk)}$	-	ns
$t_d(AV)$	address valid delay time	-	$3.8 + 0.5 \times T_{cy(clk)}$	$6.3 + 0.5 \times T_{cy(clk)}$	ns
$t_h(A)$	address hold time	$0.3 + 0.5 \times T_{cy(clk)}$	$0.9 + 0.5 \times T_{cy(clk)}$	-	ns
$t_d(CKEOUTV)$	CKEOUT valid delay time	-	$3.1 + 0.5 \times T_{cy(clk)}$	$5.1 + 0.5 \times T_{cy(clk)}$	ns
$t_h(CKEOUT)$	CKEOUT hold time	$0.5 \times T_{cy(clk)}$	$0.7 + 0.5 \times T_{cy(clk)}$	-	ns
Read cycle parameters					
$t_{su}(D)$	data input set-up time	-1.5	-0.5	-	ns
$t_h(D)$	data input hold time	2.2	0.8	-	ns
Write cycle parameters					
$t_d(QV)$	data output valid delay time	-	$3.8 + 0.5 \times T_{cy(clk)}$	$6.2 + 0.5 \times T_{cy(clk)}$	ns
$t_h(Q)$	data output hold time	$0.5 \times T_{cy(clk)}$	$0.7 + 0.5 \times T_{cy(clk)}$	-	ns

Table 30. Dynamic characteristics: Dynamic external memory interface; EMC_CLK[3:0] delay values

$T_{amb} = -40$ °C to 105 °C; $V_{DD(IO)} = 3.3\text{ V} \pm 10\%$; $2.4\text{ V} \leq V_{DD(REG)(3V3)} \leq 3.6\text{ V}$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t_d	delay time	delay value [1]				
		CLKn_DELAY = 0	0.0	0.0	0.0	ns
		CLKn_DELAY = 1 [1]	0.4	0.5	0.8	ns
		CLKn_DELAY = 2 [1]	0.7	1.0	1.7	ns
		CLKn_DELAY = 3 [1]	1.1	1.6	2.5	ns
		CLKn_DELAY = 4 [1]	1.4	2.0	3.3	ns
		CLKn_DELAY = 5 [1]	1.7	2.6	4.1	ns
		CLKn_DELAY = 6 [1]	2.1	3.1	4.9	ns
		CLKn_DELAY = 7 [1]	2.5	3.6	5.8	ns

[1] Program the EMC_CLKn delay values in the EMCDELAYCLK register (see the LPC18xx User manual). The delay values must be the same for all SDRAM clocks EMC_CLKn: $CLK0_DELAY = CLK1_DELAY = CLK2_DELAY = CLK3_DELAY$.

11.14 USB interface

Table 31. Dynamic characteristics: USB0 and USB1 pins (full-speed)

$C_L = 50\text{ pF}$; $R_{pu} = 1.5\text{ k}\Omega$ on D+ to $V_{DD(I/O)}$, unless otherwise specified; $3.0\text{ V} \leq V_{DD(I/O)} \leq 3.6\text{ V}$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t_r	rise time	10 % to 90 %	4.0	-	20.0	ns
t_f	fall time	10 % to 90 %	4.0	-	20.0	ns
t_{FRFM}	differential rise and fall time matching	t_r / t_f	90	-	111.11	%
V_{CRS}	output signal crossover voltage		1.3	-	2.0	V
t_{FEOPT}	source SE0 interval of EOP	see Figure 35	160	-	175	ns
t_{FDEOP}	source jitter for differential transition to SE0 transition	see Figure 35	-2	-	+5	ns
t_{JR1}	receiver jitter to next transition		-18.5	-	+18.5	ns
t_{JR2}	receiver jitter for paired transitions	10 % to 90 %	-9	-	+9	ns
t_{EOPR1}	EOP width at receiver	must reject as EOP; see Figure 35	[1] 40	-	-	ns
t_{EOPR2}	EOP width at receiver	must accept as EOP; see Figure 35	[1] 82	-	-	ns

[1] Characterized but not implemented as production test. Guaranteed by design.

Remark: If only USB0 (HS USB) is used, the pins VDDREG and VDDIO can be at different voltages within the operating range but should have the same ramp up time. If USB1(FS USB) is used, the pins VDDREG and VDDIO should be a minimum of 3.0 V and be tied together.

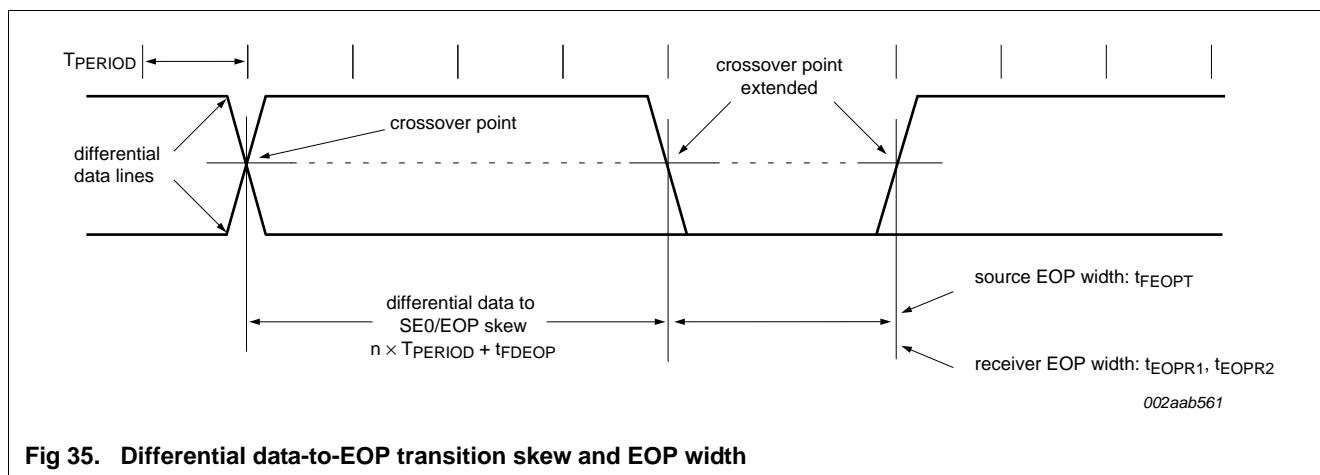


Fig 35. Differential data-to-EOP transition skew and EOP width

Table 40. LCD panel connections for STN dual panel mode

External pin	4-bit mono STN dual panel		8-bit mono STN dual panel		Color STN dual panel	
	LPC18xx pin used	LCD function	LPC18xx pin used	LCD function	LPC18xx pin used	LCD function
LCD_VD2	P4_3	UD[2]	P4_3	UD[2]	P4_3	UD[2]
LCD_VD1	P4_4	UD[1]	P4_4	UD[1]	P4_4	UD[1]
LCD_VD0	P4_1	UD[0]	P4_1	UD[0]	P4_1	UD[0]
LCD_LP	P7_6	LCDLP	P7_6	LCDLP	P7_6	LCDLP
LCD_ENAB/ LCDM	P4_6	LCDENAB/ LCDM	P4_6	LCDENAB/ LCDM	P4_6	LCDENAB/ LCDM
LCD_FP	P4_5	LCDFP	P4_5	LCDFP	P4_5	LCDFP
LCD_DCLK	P4_7	LCDDCLK	P4_7	LCDDCLK	P4_7	LCDDCLK
LCD_LE	P7_0	LCDLE	P7_0	LCDLE	P7_0	LCDLE
LCD_PWR	P7_7	LCDPWR	P7_7	LCDPWR	P7_7	LCDPWR
GP_CLKIN	PF_4	LCDCLKIN	PF_4	LCDCLKIN	PF_4	LCDCLKIN

Table 41. LCD panel connections for TFT panels

External pin	TFT 12 bit (4:4:4 mode)		TFT 16 bit (5:6:5 mode)		TFT 16 bit (1:5:5:5 mode)		TFT 24 bit	
	LPC18xx pin used	LCD function	LPC18xx pin used	LCD function	LPC18xx pin used	LCD function	LPC18xx pin used	LCD function
LCD_VD23	PB_0	BLUE3	PB_0	BLUE4	PB_0	BLUE4		BLUE7
LCD_VD22	PB_1	BLUE2	PB_1	BLUE3	PB_1	BLUE3		BLUE6
LCD_VD21	PB_2	BLUE1	PB_2	BLUE2	PB_2	BLUE2		BLUE5
LCD_VD20	PB_3	BLUE0	PB_3	BLUE1	PB_3	BLUE1		BLUE4
LCD_VD19	-	-	P7_1	BLUE0	P7_1	BLUE0		BLUE3
LCD_VD18	-	-	-	-	P7_2	intensity		BLUE2
LCD_VD17	-	-	-	-	-	-	P7_3	BLUE1
LCD_VD16	-	-	-	-	-	-	P7_4	BLUE0
LCD_VD15	PB_4	GREEN3	PB_4	GREEN5	PB_4	GREEN4	PB_4	GREEN7
LCD_VD14	PB_5	GREEN2	PB_5	GREEN4	PB_5	GREEN3	PB_5	GREEN6
LCD_VD13	PB_6	GREEN1	PB_6	GREEN3	PB_6	GREEN2	PB_6	GREEN5
LCD_VD12	P8_3	GREEN0	P8_3	GREEN2	P8_3	GREEN1	P8_3	GREEN4
LCD_VD11	-	-	P4_9	GREEN1	P4_9	GREEN0	P4_9	GREEN3
LCD_VD10	-	-	P4_10	GREEN0	P4_10	intensity	P4_10	GREEN2
LCD_VD9	-	-	-	-	-	-	P4_8	GREEN1
LCD_VD8	-	-	-	-	-	-	P7_5	GREEN0
LCD_VD7	P8_4	RED3	P8_4	RED4	P8_4	RED4	P8_4	RED7
LCD_VD6	P8_5	RED2	P8_5	RED3	P8_5	RED3	P8_5	RED6
LCD_VD5	P8_6	RED1	P8_6	RED2	P8_6	RED2	P8_6	RED5
LCD_VD4	P8_7	RED0	P8_7	RED1	P8_7	RED1	P8_7	RED4
LCD_VD3	-	-	P4_2	RED0	P4_2	RED0	P4_2	RED3
LCD_VD2	-	-	-	-	P4_3	intensity	P4_3	RED2
LCD_VD1	-	-	-	-	-	-	P4_4	RED1

16. Abbreviations

Table 44. Abbreviations

Acronym	Description
ADC	Analog-to-Digital Converter
AHB	Advanced High-performance Bus
APB	Advanced Peripheral Bus
API	Application Programming Interface
BOD	BrownOut Detection
BGA	Ball Grid Array
CAN	Controller Area Network
CMAC	Cipher-based Message Authentication Code
CSMA/CD	Carrier Sense Multiple Access with Collision Detection
DAC	Digital-to-Analog Converter
DMA	Direct Memory Access
EOP	End Of Packet
ETB	Embedded Trace Buffer
ETM	Embedded Trace Macrocell
GPIO	General-Purpose Input/Output
IRC	Internal RC
IrDA	Infrared Data Association
JTAG	Joint Test Action Group
LCD	Liquid Crystal Display
LSB	Least Significant Bit
LQFP	Low Quad Flat Package
MAC	Media Access Control
MCU	MicroController Unit
MIIM	Media Independent Interface Management
n.c.	not connected
OTG	On-The-Go
PHY	PHYsical layer
PLL	Phase-Locked Loop
PWM	Pulse Width Modulator
RMII	Reduced Media Independent Interface
SDRAM	Synchronous Dynamic Random Access Memory
SPI	Serial Peripheral Interface
SSI	Serial Synchronous Interface
SSP	Synchronous Serial Port
TCP/IP	Transmission Control Protocol/Internet Protocol
TTL	Transistor-Transistor Logic
UART	Universal Asynchronous Receiver/Transmitter
ULPI	UTMI+ Low Pin Interface

Table 45. Revision history ...continued

Document ID	Release date	Data sheet status	Change notice	Supersedes
Modifications:	<ul style="list-style-type: none"> • Minimum operating voltage changed from 2.2 V to 2.4 V for $V_{DD(REG)(3V3)}$, $V_{DD(IO)}$, $V_{DDA(3V3)}$, V_{BAT} in Table 11. • Updated Dynamic characteristics: SSP pins in SPI mode. See Table 27. • Updated Dynamic characteristics: SD/MMC. See Table 34. • SPIFI timing data restated for $CL = 20$ pF in Table 36 "Dynamic characteristics: SPIFI". • SPIFI timing diagram corrected and specified for mode 0. See Table 36 and Figure 38. • Table 23 "Dynamic characteristic: I/O pins[1]" added. • Parameter CI corrected for high-drive pins (changed from 2 pF to 5.2 pF). See Table 11. • Internal pull-up resistor configuration added for \overline{RESET}, WAKEUPn, and ALARM pins. See Table 3. • Description of DEBUG pin updated. • Input range for PLL1 corrected: 1 MHz to 25 MHz. See Section 7.20.7 "System PLL1". • Signal polarity corrected for pins EMC_CKEOUT and EMC_DQMOUT. Both signals are active HIGH. • Updated USART timing figure. See Figure 29 "USART timing". • Updated USART Dynamic characteristics table. See Table 26. • USB0_VBUS changed to input only. See Table 3 "Pin description" • SPIFI output timing parameters in Table 36 corrected to apply to Mode 0: <ul style="list-style-type: none"> – $t_{v(Q)}$ changed to 3.2 ns. – $t_{h(Q)}$ changed to 0.6 ns, • Parameter t_{CSLWEL} with condition $PB = 1$ corrected: $(WAITWEN + 1) \times T_{cy(clk)}$ added. See Table 28 "Dynamic characteristics: Static asynchronous external memory interface". • Parameter $t_{CSLBLSL}$ with condition $PB = 0$ corrected: $(WAITWEN + 1) \times T_{cy(clk)}$ added. See Table 28 "Dynamic characteristics: Static asynchronous external memory interface". • Removed restriction on C_CAN bus usage. See CAN.1 errata in Ref. 2. • Updated Figure 30, SSP master timing in SPI mode and Figure 31, SSP slave timing in SPI mode. • Changed the flash erase time (t_{er}) to 100ms. See Table 15. • Updated Dynamic characteristics: USB0 and USB1 pins (full-speed). See Table 31. • Updated Dynamic characteristics: SD/MMC table. See Table 34. • Updated Table 2: Motor control PWM instead of PWM. • Added a remark to Table 31. • Updated Table 13 "BOD static characteristics[1]". Removed BOD interrupt levels 0 and 1; removed Reset levels 0 and 1. They are not applicable. 			
LPC185X_3X_2X_1X v.4.1	<td>	Product data sheet	-	LPC185X_3X_2X_1X v.4

19. Legal information

19.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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